Infineon Technologies - MB96F346RSBPMC-GSE2 Datasheet

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What is "Embedded - Microcontrollers"?

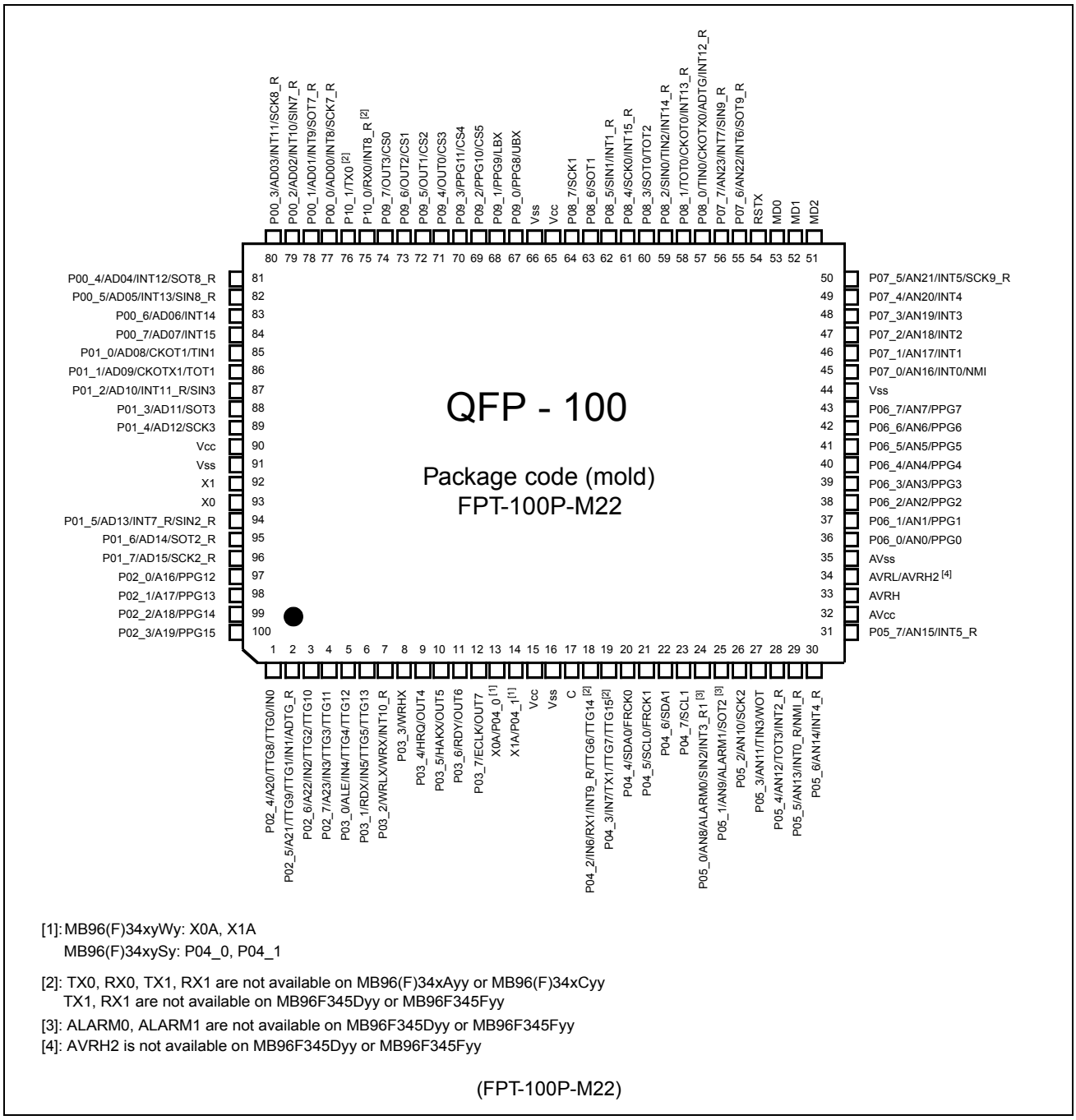
"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Discontinued at Digi-Key
Core Processor	F²MC-16FX
Core Size	16-Bit
Speed	56MHz
Connectivity	CANbus, EBI/EMI, I²C, LINbus, SCI, UART/USART
Peripherals	DMA, LVD, LVR, POR, PWM, WDT
Number of I/O	82
Program Memory Size	288KB (288K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	16K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	A/D 24x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	100-LQFP
Supplier Device Package	100-LQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/mb96f346rsbpmc-gse2

3. Pin Assignments

Figure 2. Pin assignment of MB96(F)34x (FPT-100P-M22)



[1]: MB96(F)34xyWy: X0A, X1A
MB96(F)34xySy: P04_0, P04_1

[2]: TX0, RX0, TX1, RX1 are not available on MB96(F)34xAyy or MB96(F)34xCyy
TX1, RX1 are not available on MB96F345Dyy or MB96F345Fyy

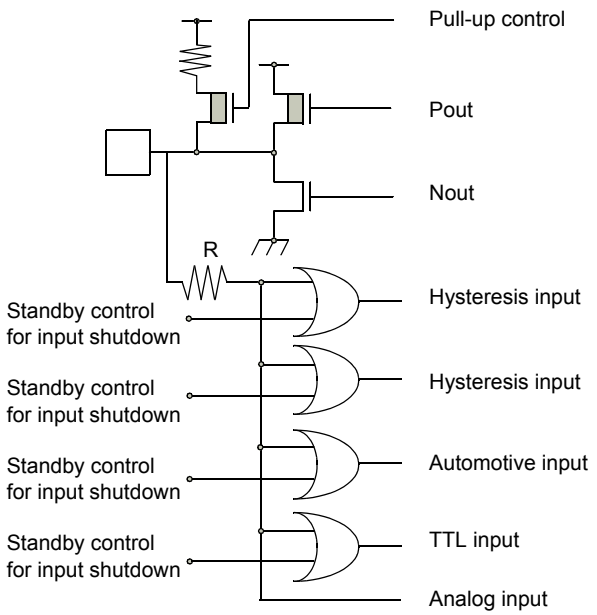
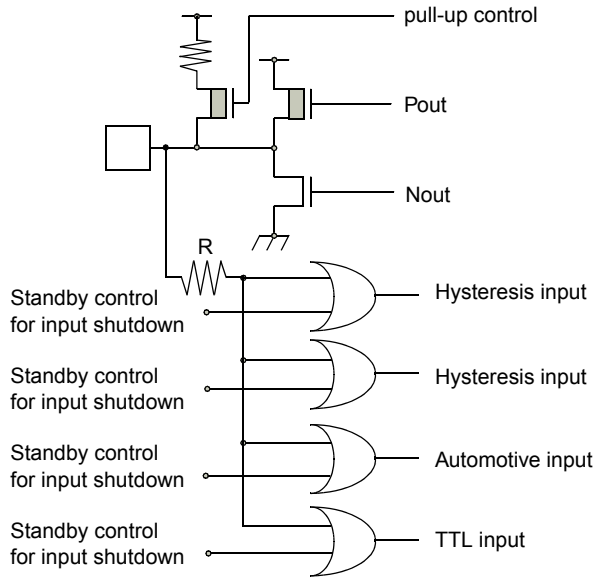
[3]: ALARM0, ALARM1 are not available on MB96F345Dyy or MB96F345Fyy

[4]: AVRH2 is not available on MB96F345Dyy or MB96F345Fyy

(FPT-100P-M22)

Remark:

MB96(F)34x products are pin-compatible to F^{2}MC-16LX family MB90340 series.

Type	Circuit	Remarks
I		■ CMOS level output (programmable I_{OL} = 5mA, I_{OH} = -5mA and I_{OL} = 2mA, I_{OH} = -2mA) ■ 2 different CMOS hysteresis inputs with input shutdown function * ■ Automotive input with input shutdown function ■ TTL input with input shutdown function * ■ Programmable pull-up resistor: 50kΩ approx. ■ Analog input *MB96F345Dyy or MB96F345Fyy: Only Automotive input and CMOS hysteresis input (0.7/0.3) are supported
N		■ CMOS level output (I_{OL} = 3mA, I_{OH} = -3mA) ■ 2 different CMOS hysteresis inputs with input shutdown function * ■ Automotive input with input shutdown function ■ TTL input with input shutdown function * ■ Programmable pull-up resistor: 50kΩ approx. *MB96F345Dyy or MB96F345Fyy: Only Automotive input and CMOS hysteresis input (0.7/0.3) are supported

■ RAM Start/End and External Bus End Addresses

Devices	Bank 0 RAM size	Bank 1 RAM size	External Bus end address	RAMSTART0	RAMSTART1	RAMEND1
MB96(F)345	8KByte	-	$00:21FF_H$	$00:6240_H$	-	-
MB96(F)346,MB96F347	16KByte	-	$00:21FF_H$	$00:4240_H$	-	-
MB96F348	24KByte	-	$00:21FF_H$	$00:2240_H$	-	-

10. Serial Programming Communication Interface

Table 3: USART pins for Flash serial programming (MD[2:0] = 010, Serial Communication mode)

MB96F34x			
Pin number	Pin number	USART Number	Normal function
LQFP-100	QFP-100		
57	59	USART0	SIN0
58	60		SOT0
59	61		SCK0
60	62	USART1	SIN1
61	63		SOT1
62	64		SCK1
22	24	USART2	SIN2
23	25		SOT2
24	26		SCK2
85	87	USART3	SIN3
86	88		SOT3
87	89		SCK3

Note: If a Flash programmer and its software needs to use a handshaking pin, Cypress suggests to the tool vendor to support at least port P00_1 on pin 76/78.If handshaking is used by the tool but P00_1 is not available in customer's application, Cypress suggests to the customer to check the tool manual or to contact the tool vendor for alternative handshaking pins.

Table 4: I/O map MB96(F)34x

Address	Register	Abbreviation 8-bit access	Abbreviation 16-bit access	Access
$0000C1_H$	USART0 - Serial Control Register	SCR0		R/W
$0000C2_H$	USART0 - TX Register	TDR0		W
$0000C2_H$	USART0 - RX Register	RDR0		R
$0000C3_H$	USART0 - Serial Status	SSR0		R/W
$0000C4_H$	USART0 - Control/Com. Register	ECCR0		R/W
$0000C5_H$	USART0 - Ext. Status Register	ESCR0		R/W
$0000C6_H$	USART0 - Baud Rate Generator Register Low	BGRL0	BGR0	R/W
$0000C7_H$	USART0 - Baud Rate Generator Register High	BGRH0		R/W
$0000C8_H$	USART0 - Extended Serial Interrupt Register	ESIR0		R/W
$0000C9_H$	Reserved			-
$0000CA_H$	USART1 - Serial Mode Register	SMR1		R/W
$0000CB_H$	USART1 - Serial Control Register	SCR1		R/W
$0000CC_H$	USART1 - TX Register	TDR1		W
$0000CC_H$	USART1 - RX Register	RDR1		R
$0000CD_H$	USART1 - Serial Status	SSR1		R/W
$0000CE_H$	USART1 - Control/Com. Register	ECCR1		R/W
$0000CF_H$	USART1 - Ext. Status Register	ESCR1		R/W
$0000D0_H$	USART1 - Baud Rate Generator Register Low	BGRL1	BGR1	R/W
$0000D1_H$	USART1 - Baud Rate Generator Register High	BGRH1		R/W
$0000D2_H$	USART1 - Extended Serial Interrupt Register	ESIR1		R/W
$0000D3_H$	Reserved			-
$0000D4_H$	USART2 - Serial Mode Register	SMR2		R/W
$0000D5_H$	USART2 - Serial Control Register	SCR2		R/W
$0000D6_H$	USART2 - TX Register	TDR2		W
$0000D6_H$	USART2 - RX Register	RDR2		R
$0000D7_H$	USART2 - Serial Status	SSR2		R/W
$0000D8_H$	USART2 - Control/Com. Register	ECCR2		R/W
$0000D9_H$	USART2 - Ext. Status Register	ESCR2		R/W
$0000DA_H$	USART2 - Baud Rate Generator Register Low	BGRL2	BGR2	R/W
$0000DB_H$	USART2 - Baud Rate Generator Register High	BGRH2		R/W
$0000DC_H$	USART2 - Extended Serial Interrupt Register	ESIR2		R/W
$0000DD_H$	Reserved			-

Table 4: I/O map MB96(F)34x

Address	Register	Abbreviation 8-bit access	Abbreviation 16-bit access	Access
$0003D9_H$	Memory Patch function - Patch data 4 High	PFDH4		R/W
$0003DA_H$	Memory Patch function - Patch data 5 Low	PFDL5	PFD5	R/W
$0003DB_H$	Memory Patch function - Patch data 5 High	PFDH5		R/W
$0003DC_H$	Memory Patch function - Patch data 6 Low	PFDL6	PFD6	R/W
$0003DD_H$	Memory Patch function - Patch data 6 High	PFDH6		R/W
$0003DE_H$	Memory Patch function - Patch data 7 Low	PFDL7	PFD7	R/W
$0003DF_H$	Memory Patch function - Patch data 7 High	PFDH7		R/W
$0003E0_H$	Data Flash Control and Status register A	DFCSA		R/W
$0003E1_H$	Data Flash Write command sequencer Control register A	DFWCA		R/W
$0003E2_H$	Data Flash Write command sequencer Status register A	DFWSA		R/W
$0003E3_H$-$0003F0_H$	Reserved			-
$0003F1_H$	Memory Control Status Register A	MCSRA		R/W
$0003F2_H$	Memory Timing Configuration Register A Low	MTCRAL	MTCRA	R/W
$0003F3_H$	Memory Timing Configuration Register A High	MTCRAH		R/W
$0003F4_H$	Reserved			-
$0003F5_H$	Memory Control Status Register B	MCSRB		R/W
$0003F6_H$	Memory Timing Configuration Register B Low	MTCRBL	MTCRB	R/W
$0003F7_H$	Memory Timing Configuration Register B High	MTCRBH		R/W
$0003F8_H$	Flash Memory Write Control register 0	FMWC0		R/W
$0003F9_H$	Flash Memory Write Control register 1	FMWC1		R/W
$0003FA_H$	Flash Memory Write Control register 2	FMWC2		R/W
$0003FB_H$	Flash Memory Write Control register 3	FMWC3		R/W
$0003FC_H$	Flash Memory Write Control register 4	FMWC4		R/W
$0003FD_H$	Flash Memory Write Control register 5	FMWC5		R/W
$0003FE_H$-$0003FF_H$	Reserved			-
000400_H	Standby Mode control register	SMCR		R/W
000401_H	Clock select register	CKSR		R/W
000402_H	Clock Stabilization select register	CKSSR		R/W
000403_H	Clock monitor register	CKMR		R
000404_H	Clock Frequency control register Low	CKFCRL	CKFCR	R/W
000405_H	Clock Frequency control register High	CKFCRH		R/W
000406_H	PLL Control register Low	PLLCRL	PLLCR	R/W

Table 4: I/O map MB96(F)34x

Address	Register	Abbreviation 8-bit access	Abbreviation 16-bit access	Access
$0005AD_H$	PPG14 - Timer register			R
$0005AE_H$	PPG14 - Period setting register		PCSR14	W
$0005AF_H$	PPG14 - Period setting register			W
$0005B0_H$	PPG14 - Duty cycle register		PDUT14	W
$0005B1_H$	PPG14 - Duty cycle register			W
$0005B2_H$	PPG14 - Control status register Low	PCNL14	PCN14	R/W
$0005B3_H$	PPG14 - Control status register High	PCNH14		R/W
$0005B4_H$	PPG15 - Timer register		PTMR15	R
$0005B5_H$	PPG15 - Timer register			R
$0005B6_H$	PPG15 - Period setting register		PCSR15	W
$0005B7_H$	PPG15 - Period setting register			W
$0005B8_H$	PPG15 - Duty cycle register		PDUT15	W
$0005B9_H$	PPG15 - Duty cycle register			W
$0005BA_H$	PPG15 - Control status register Low	PCNL15	PCN15	R/W
$0005BB_H$	PPG15 - Control status register High	PCNH15		R/W
$0005BC_H$-$00065F_H$	Reserved			-
000660_H	Peripheral Resource Relocation Register 10	PRRR10		R/W
000661_H	Peripheral Resource Relocation Register 11	PRRR11		R/W
000662_H	Peripheral Resource Relocation Register 12	PRRR12		R/W
000663_H	Peripheral Resource Relocation Register 13	PRRR13		W
000664_H-$0006DF_H$	Reserved			-
$0006E0_H$	External Bus - Area configuration register 0 Low	EACL0	EAC0	R/W
$0006E1_H$	External Bus - Area configuration register 0 High	EACH0		R/W
$0006E2_H$	External Bus - Area configuration register 1 Low	EACL1	EAC1	R/W
$0006E3_H$	External Bus - Area configuration register 1 High	EACH1		R/W
$0006E4_H$	External Bus - Area configuration register 2 Low	EACL2	EAC2	R/W
$0006E5_H$	External Bus - Area configuration register 2 High	EACH2		R/W
$0006E6_H$	External Bus - Area configuration register 3 Low	EACL3	EAC3	R/W
$0006E7_H$	External Bus - Area configuration register 3 High	EACH3		R/W
$0006E8_H$	External Bus - Area configuration register 4 Low	EACL4	EAC4	R/W
$0006E9_H$	External Bus - Area configuration register 4 High	EACH4		R/W
$0006EA_H$	External Bus - Area configuration register 5 Low	EACL5	EAC5	R/W

Table 4: I/O map MB96(F)34x

Address	Register	Abbreviation 8-bit access	Abbreviation 16-bit access	Access
$0006EB_H$	External Bus - Area configuration register 5 High	EACH5		R/W
$0006EC_H$	External Bus - Area select register 2	EAS2		R/W
$0006ED_H$	External Bus - Area select register 3	EAS3		R/W
$0006EE_H$	External Bus - Area select register 4	EAS4		R/W
$0006EF_H$	External Bus - Area select register 5	EAS5		R/W
$0006F0_H$	External Bus - Mode register	EBM		R/W
$0006F1_H$	External Bus - Clock and Function register	EBCF		R/W
$0006F2_H$	External Bus - Address output enable register 0	EBAE0		R/W
$0006F3_H$	External Bus - Address output enable register 1	EBAE1		R/W
$0006F4_H$	External Bus - Address output enable register 2	EBAE2		R/W
$0006F5_H$	External Bus - Control signal register	EBCS		R/W
$0006F6_H$-$0006FF_H$	Reserved			-
000700_H	CAN0 - Control register Low	CTRLRL0	CTRLR0	R/W
000701_H	CAN0 - Control register High (reserved)	CTRLRH0		R
000702_H	CAN0 - Status register Low	STATRL0	STATR0	R/W
000703_H	CAN0 - Status register High (reserved)	STATRH0		R
000704_H	CAN0 - Error Counter Low (Transmit)	ERRCNTL0	ERRCNT0	R
000705_H	CAN0 - Error Counter High (Receive)	ERRCNTH0		R
000706_H	CAN0 - Bit Timing Register Low	BTRL0	BTR0	R/W
000707_H	CAN0 - Bit Timing Register High	BTRH0		R/W
000708_H	CAN0 - Interrupt Register Low	INTRL0	INTR0	R
000709_H	CAN0 - Interrupt Register High	INTRH0		R
$00070A_H$	CAN0 - Test Register Low	TESTRL0	TESTR0	R/W
$00070B_H$	CAN0 - Test Register High (reserved)	TESTRH0		R
$00070C_H$	CAN0 - BRP Extension register Low	BRPERL0	BRPER0	R/W
$00070D_H$	CAN0 - BRP Extension register High (reserved)	BRPERH0		R
$00070E_H$-$00070F_H$	Reserved			-
000710_H	CAN0 - IF1 Command request register Low	IF1CREQL0	IF1CREQ0	R/W
000711_H	CAN0 - IF1 Command request register High	IF1CREQH0		R/W
000712_H	CAN0 - IF1 Command Mask register Low	IF1CMSKL0	IF1CMSK0	R/W
000713_H	CAN0 - IF1 Command Mask register High (reserved)	IF1CMSKH0		R
000714_H	CAN0 - IF1 Mask 1 Register Low	IF1MSK1L0	IF1MSK10	R/W

Table 4: I/O map MB96(F)34x

Address	Register	Abbreviation 8-bit access	Abbreviation 16-bit access	Access
000884_H-$00088F_H$	Reserved			-
000890_H	CAN1 - New Data 1 Register Low	NEWDT1L1	NEWDT11	R
000891_H	CAN1 - New Data 1 Register High	NEWDT1H1		R
000892_H	CAN1 - New Data 2 Register Low	NEWDT2L1	NEWDT21	R
000893_H	CAN1 - New Data 2 Register High	NEWDT2H1		R
000894_H-$00089F_H$	Reserved			-
$0008A0_H$	CAN1 - Interrupt Pending 1 Register Low	INTPND1L1	INTPND11	R
$0008A1_H$	CAN1 - Interrupt Pending 1 Register High	INTPND1H1		R
$0008A2_H$	CAN1 - Interrupt Pending 2 Register Low	INTPND2L1	INTPND21	R
$0008A3_H$	CAN1 - Interrupt Pending 2 Register High	INTPND2H1		R
$0008A4_H$-$0008AF_H$	Reserved			-
$0008B0_H$	CAN1 - Message Valid 1 Register Low	MSGVAL1L1	MSGVAL11	R
$0008B1_H$	CAN1 - Message Valid 1 Register High	MSGVAL1H1		R
$0008B2_H$	CAN1 - Message Valid 2 Register Low	MSGVAL2L1	MSGVAL21	R
$0008B3_H$	CAN1 - Message Valid 2 Register High	MSGVAL2H1		R
$0008B4_H$-$0008CD_H$	Reserved			-
$0008CE_H$	CAN1 - Output enable register	COER1		R/W
$0008CF_H$-$0009FF_H$	Reserved			-
$000A00_H$	DMA - IO address block register 0	IOABK0		R/W
$000A01_H$	DMA - IO address block register 1	IOABK1		R/W
$000A02_H$	DMA - IO address block register 2	IOABK2		R/W
$000A03_H$	DMA - IO address block register 3	IOABK3		R/W
$000A04_H$	DMA - IO address block register 4	IOABK4		R/W
$000A05_H$	DMA - IO address block register 5	IOABK5		R/W
$000A06_H$-$000BFF_H$	Reserved			-

Note: Any write access to reserved addresses in the I/O map should not be performed. A read access to a reserved address results in reading ‘X’.Registers of resources which are described in this table, but which are not supported by the device, should also be handled as “Reserved”.

[4]: The maximum permitted power dissipation depends on the ambient temperature, the air flow velocity and the thermal conductance of the package on the PCB.The actual power dissipation depends on the customer application and can be calculated as follows:
$P_D = P_{IO} + P_{INT}$
$P_{IO} = \Sigma (V_{OL} * I_{OL} + V_{OH} * I_{OH})$ (IO load power dissipation, sum is performed on all IO ports)
$P_{INT} = V_{CC} * (I_{CC} + I_A)$ (internal power dissipation)
I_{CC} is the total core current consumption into V_{CC} as described in the “DC characteristics” and depends on the selected operation mode and clock frequency and the usage of functions like Flash programming or the clock modulator.I_A is the analog current consumption into AV_{CC}.

[5]: Worst case value for a package mounted on single layer PCB at specified T_A without air flow.

[6]: Please contact Cypress for reliability limitations when using under these conditions.

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed any of these ratings.

14.2 Recommended Operating Conditions

Parameter	Symbol	Value			Unit	Remarks
		Min	Typ	Max		
Power supply voltage	V_{CC}	3.0	-	5.5	V	
Smoothing capacitor at C pin	C_S	3.5	4.7 - 10	15	µF	Use a low inductance capacitor (for example X7R ceramic capacitor)

WARNING: The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.

Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their representatives beforehand.

(T_A = -40°C to 125°C, V_{CC} = AV_{CC} = 3.0V to 5.5V, V_{SS} = AV_{SS} = 0V)

Parameter	Symbol	Condition (at T_A)		Value			Remarks
				Typ	Max	Unit	
Power supply current in Timer modes[1]	I_{CCTRCL}	RC Timer mode with CLKRC = 100kHz, SMCR:LPMSS = 0 (CLKMC, CLKPLL and CLKSC stopped. Voltage regulator in high power mode)	+25°C	0.3	0.45	mA	MB96F346/F347/F348
			+125°C	0.8	3.2		
			+25°C	0.08	0.15	mA	MB96F345
			+125°C	0.58	2.95		
			+25°C	0.3	0.45	mA	MB96345/346
			+125°C	0.8	2.2		
		RC Timer mode with CLKRC = 100kHz, SMCR:LPMSS = 1 (CLKMC, CLKPLL and CLKSC stopped. Voltage regulator in low power mode)	+25°C	0.05	0.1	mA	Flash devices
			+125°C	0.55	2.85		
			+25°C	0.05	0.1	mA	MB96345/346
			+125°C	0.55	1.85		
	I_{CCTSUB}	Sub Timer mode with CLKSC = 32kHz (CLKMC, CLKPLL and CLKRC stopped)	+25°C	0.03	0.1	mA	Flash devices
			+125°C	0.53	2.85		
			+25°C	0.03	0.1	mA	MB96345/346
			+125°C	0.53	1.85		
Power supply current in Stop Mode	I_{CCH}	VRCR:LPMB[2:0] = 110_B (Core voltage at 1.8V)	+25°C	0.02	0.08	mA	Flash devices
			+125°C	0.52	2.8		
			+25°C	0.02	0.08	mA	MB96345/346
			+125°C	0.52	1.8		
		VRCR:LPMB[2:0] = 000_B (Core voltage at 1.2V)	+25°C	0.015	0.06	mA	Flash devices
			+125°C	0.4	2.3		
			+25°C	0.015	0.06	mA	MB96345/346
			+125°C	0.4	1.4		
Power supply current for active Low Voltage detector	I_{CCLVD}	Low voltage detector enabled (RCR:LVDE = 1)	-	5	10	µA	MB96F345 Must be added to all current above
			+25°C	90	140	µA	Other devices Must be added to all current above
			+125°C	100	150		

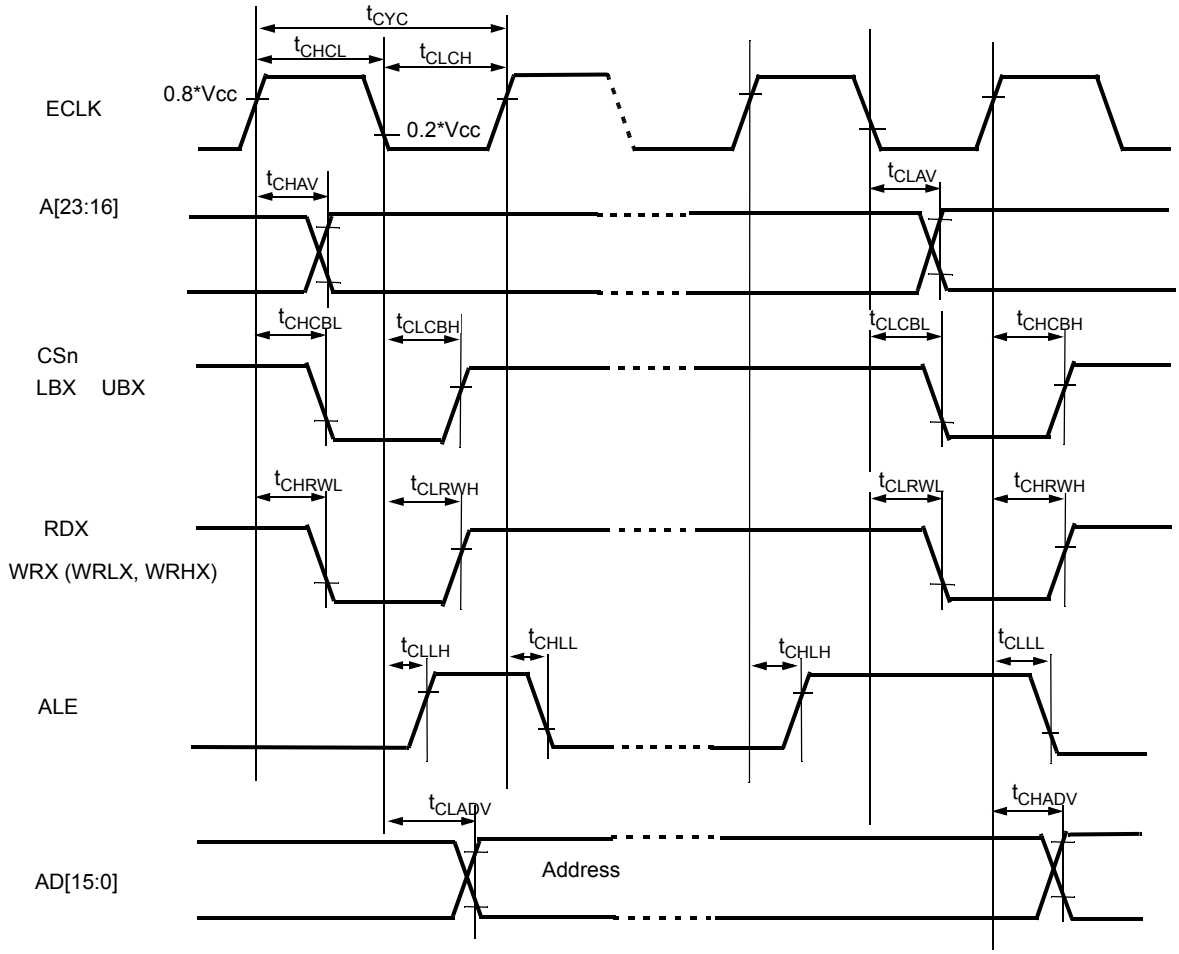
(T_A = -40°C to 125°C, V_{CC} = AV_{CC} = 3.0V to 5.5V, V_{SS} = AV_{SS} = 0V)

Parameter	Symbol	Condition (at T_A)		Value			Remarks
				Typ	Max	Unit	
Power supply current for active Clock modulator	$I_{CCCLOMO}$	Clock modulator enabled (CMCR:PDX = 1)	-	3	4.5	mA	Must be added to all current above
Flash Write/Erase current	$I_{CCFLASH}$	Current for one Flash module	-	15	40	mA	Must be added to all current above
	$I_{CCDFLASH}$	Current for one Data Flash module		10	20	mA	Must be added to all current above
Input capacitance	C_{IN}	-	-	5	15	pF	Other than C, AV_{CC}, AV_{SS}, AVRH, AVRL, V_{CC}, V_{SS}
[1]: The power supply current is measured with a 4MHz external clock connected to the Main oscillator and a 32kHz external clock connected to the Sub oscillator. See chapter “Standby mode and voltage regulator control circuit” of the Hardware Manual for further details about voltage regulator control.							

14.4.7 Basic Timing

(T_A = –40°C to +125°C, V_{CC} = 5.0 V ± 10%, V_{SS} = 0.0 V, IO_{drive} = 5mA, C_L = 50pF)

Parameter	Symbol	Pin	Condition	Value		Unit	Remarks
				Min	Max		
ECLK	t_{CYC}	ECLK	-	25	-	ns	
	t_{CHCL}			t_{CYC}/2-5	t_{CYC}/2+5		
	t_{CLCH}			t_{CYC}/2-5	t_{CYC}/2+5		
ECLK → UBX/ LBX / CSn time	t_{CHCBH}	CSn, UBX, LBX, ECLK	-	-20	20	ns	
	t_{CHCBL}			-20	20		
	t_{CLCBH}			-20	20		
	t_{CLCBL}			-20	20		
ECLK → ALE time	t_{CHLH}	ALE, ECLK	-	-10	10	ns	
	t_{CHLL}			-10	10		
	t_{CLLH}			-10	10		
	t_{CLLL}			-10	10		
ECLK → address valid time	t_{CHAV}	A[23:16], ECLK	-	-15	15	ns	
	t_{CLAV}			-15	15		
	t_{CLADV}	AD[15:0], ECLK	-	-15	15	ns	
	t_{CHADV}			-15	15		
ECLK → RDX /WRX time	t_{CHRWH}	RDX, WRX, WRLX,WRHX, ECLK	-	-10	10	ns	
	t_{CHRWL}			-10	10		
	t_{CLRWH}			-10	10		
	t_{CLRWL}			-10	10		



Refer to the Hardware Manual for detailed Timing Charts

14.4.12 USART timing

WARNING: The values given below are for an I/O driving strength IO_{drive} = 5mA. If IO_{drive} is 2mA, all the maximum output timing described in the different tables must then be increased by 10ns.

(T_A = -40°C to 125°C, V_{CC} = 3.0V to 5.5V, V_{SS} = AV_{SS} = 0V, IO_{drive} = 5mA, C_L = 50pF)

Parameter	Symbol	Pin	Condition	V_{CC} = AV_{CC}= 4.5V to 5.5V		V_{CC} = AV_{CC}= 3.0V to 4.5V		Unit
				Min	Max	Min	Max	
Serial clock cycle time	t_{SCYCI}	SCKn	Internal Shift Clock Mode	4 t_{CLKP1}	-	4 t_{CLKP1}	-	ns
SCK ↓→ SOT delay time	t_{SLOVI}	SCKn, SOTn		-20	+20	-30	+30	ns
SOT → SCK ↑ delay time	t_{OVSHI}	SCKn, SOTn		N*t_{CLKP1} - 20 [1]	-	N*t_{CLKP1} - 30 [1]	-	ns
Valid SIN → SCK ↑	t_{IVSHI}	SCKn, SINn		t_{CLKP1} + 45	-	t_{CLKP1} + 55	-	ns
SCK ↑→ Valid SIN hold time	t_{SHIXI}	SCKn, SINn		0	-	0	-	ns
Serial clock “L” pulse width	t_{SLSHE}	SCKn	External Shift Clock Mode	t_{CLKP1} + 10	-	t_{CLKP1} + 10	-	ns
Serial clock “H” pulse width	t_{SHSLE}	SCKn		t_{CLKP1} + 10	-	t_{CLKP1} + 10	-	ns
SCK ↓→ SOT delay time	t_{SLOVE}	SCKn, SOTn		-	2 t_{CLKP1} + 45	-	2 t_{CLKP1} + 55	ns
Valid SIN → SCK ↑	t_{IVSHE}	SCKn, SINn		t_{CLKP1}/2 + 10	-	t_{CLKP1}/2 + 10	-	ns
SCK ↑→ Valid SIN hold time	t_{SHIXE}	SCKn, SINn		t_{CLKP1} + 10	-	t_{CLKP1} + 10	-	ns
SCK fall time	t_{FE}	SCKn		-	20	-	20	ns
SCK rise time	t_{RE}	SCKn		-	20	-	20	ns

Notes:

- AC characteristic in CLK synchronized mode.
- C_L is the load capacity value of pins when testing.
- Depending on the used machine clock frequency, the maximum possible baud rate can be limited by some parameters. These parameters are shown in “MB96300 Super series HARDWARE MANUAL”.
- t_{CLKP1} is the cycle time of the peripheral clock 1 (CLKP1), Unit : ns

[1]: Parameter N depends on t_{SCYCI} and can be calculated as follows:

- if t_{SCYCI} = 2*k*t_{CLKP1}, then N = k, where k is an integer > 2
- if t_{SCYCI} = (2*k+1)*t_{CLKP1}, then N = k+1, where k is an integer > 1

Examples:

t_{SCYCI}	N
4*t_{CLKP1}	2
5*t_{CLKP1},	3
7*t_{CLKP1},	4
...	...

14.6 Alarm Comparator

(T_A = -40 °C to +125 °C, V_{CC} = AV_{CC} = 3.0V - 5.5V, V_{SS} = AV_{SS} = 0V)

Parameter	Symbol	Pin	Value			Unit	Remarks
			Min	Typ	Max		
Power supply current	I_{A5ALMF}	AV_{CC}	-	25	45	µA	Alarm comparator enabled in fast mode (one channel)
	I_{A5ALMS}		-	7	13	µA	Alarm comparator enabled in slow mode (one channel)
	I_{A5ALMH}		-	-	5	µA	Alarm comparator disabled
ALARM pin input current	I_{ALIN}	ALARM0, ALARM1	-1	-	+1	µA	T_A = 25 °C
			-3	-	+3	µA	T_A = 125 °C
ALARM pin input voltage range	V_{ALIN}		0	-	AV_{CC}	V	
External low threshold high->low transition	$V_{EVTL(H->L)}$		0.36 * AV_{CC} -0.25	0.36 * AV_{CC} -0.1	-	V	INTREF = 0
External low threshold low->high transition	$V_{EVTL(L->H)}$		-	0.36 * AV_{CC} +0.1	0.36 * AV_{CC} +0.25	V	
External high threshold high->low transition	$V_{EVTH(H->L)}$		0.78 * AV_{CC} -0.25	0.78 * AV_{CC} -0.1	-	V	
External high threshold low->high transition	$V_{EVTH(L->H)}$			0.78 * AV_{CC} +0.1	0.78 * AV_{CC} +0.25	V	
Internal low threshold high->low transition	$V_{IVTL(H->L)}$		0.9	1.1	-	V	INTREF = 1
Internal low threshold low->high transition	$V_{IVTL(L->H)}$		-	1.3	1.55	V	
Internal high threshold high->low transition	$V_{IVTH(H->L)}$		2.2	2.4	-	V	
Internal high threshold low->high transition	$V_{IVTH(L->H)}$		-	2.6	2.85	V	
Switching hysteresis	V_{HYS}		50	-	300	mV	
Comparison time	t_{COMPF}		-	0.1	1	µs	CMD = 1 (fast)
	t_{COMPS}		-	1	10	µs	CMD = 0 (slow)
Power-up stabilization time after enabling alarm comparator	t_{PD}		-	1	5	ms	Threshold levels specified above are not guaranteed within this time
Slow/Fast mode transition time	t_{CMD}		-	100	500	µs	

14.7 Low Voltage Detector Characteristics

(T_A = -40 °C to +125 °C, V_{cc} = AV_{cc} = 3.0V - 5.5V, V_{ss} = AV_{ss} = 0V)

Parameter	Symbol	Value [1]		Value [2]		Unit	Remarks
		Min	Max	Min	Max		
Stabilization time	$T_{LVDSTAB}$	-	75	-	110	µs	After power-up or change of detection level
Level 0	V_{DL0}	2.7	2.9	2.65	2.95	V	CILCR:LVL[3:0]="0000"
Level 1	V_{DL1}	2.9	3.1	2.85	3.2	V	CILCR:LVL[3:0]="0001"
Level 2	V_{DL2}	3.1	3.3	3.05	3.4	V	CILCR:LVL[3:0]="0010"
Level 3	V_{DL3}	3.5	3.75	3.45	3.85	V	CILCR:LVL[3:0]="0011"
Level 4	V_{DL4}	3.6	3.85	3.55	3.95	V	CILCR:LVL[3:0]="0100"
Level 5	V_{DL5}	3.7	3.95	3.65	4.1	V	CILCR:LVL[3:0]="0101"
Level 6	V_{DL6}	3.8	4.05	3.75	4.2	V	CILCR:LVL[3:0]="0110"
Level 7	V_{DL7}	3.9	4.15	3.85	4.3	V	CILCR:LVL[3:0]="0111"
Level 8	V_{DL8}	4.0	4.25	3.95	4.4	V	CILCR:LVL[3:0]="1000"
Level 9	V_{DL9}	4.1	4.35	4.05	4.5	V	CILCR:LVL[3:0]="1001"
Level 10	V_{DL10}	not used		not used			
Level 11	V_{DL11}	not used		not used			
Level 12	V_{DL12}	not used		not used			
Level 13	V_{DL13}	not used		not used			
Level 14	V_{DL14}	not used		not used			
Level 15	V_{DL15}	not used		not used			

[1]: valid for all devices except devices listed under "[2]"

[2]: valid for: MB96F345

CILCR:LVL[3:0] are the low voltage detector level select bits of the CILCR register.

Levels 10 to 15 are not used in this device.

For correct detection, the slope of the voltage level must satisfy $\left|\frac{dV}{dt}\right| \leq 0.004\frac{V}{\mu s}$.

Faster variations are regarded as noise and may not be detected.

The functional operation of the MCU is guaranteed down to the minimum low voltage detection level of Vcc = 2.7V. The electrical characteristics however are only valid in the specified range (usually down to 3.0V).

14.8 Flash Memory Program/erase Characteristics

(T_A = -40°C to 105°C, V_{CC} = AV_{CC} = 3.0V to 5.5V, V_{SS} = AV_{SS} = 0V)

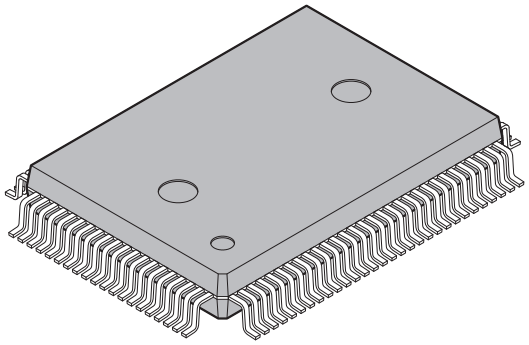
Parameter	Value			Unit	Remarks
	Min	Typ	Max		
Sector erase time Program/Data Flash (Main Flash)	-	0.9	3.6	s	Without erasure pre-programming time
Sector erase time Data Flash	-	0.5	2	s	Without erasure pre-programming time
	-	0.8	3.6	s	Including erasure pre-programming time
Chip erase time Program/Data Flash (Main Flash)	-	n*0.9	n*3.6	s	Without erasure pre-programming time (n is the number of Flash sector of the device)
Chip erase time Data Flash	-	2.5	10	s	Without erasure pre-programming time
	-	3.7	16.4	s	Including erasure pre-programming time
Word (16-bit width) programming time Program/Data Flash (Main Flash)	-	23	370	us	Without overhead time for submitting write command
Byte (8-bit width) programming time Data Flash	-	15	100	us	Without overhead time for submitting write command
Program/Erase cycle	10000	-	-	cycle	100 000 Program/Erase cycles are under evaluation by Cypress
Flash data retention time	20	-	-	year	[1]

[1]: This value was converted from the results of evaluating the reliability of the technology (using Arrhenius equation to convert high temperature measurements into normalized value at 85^{o}C)

Table 6: Used settings

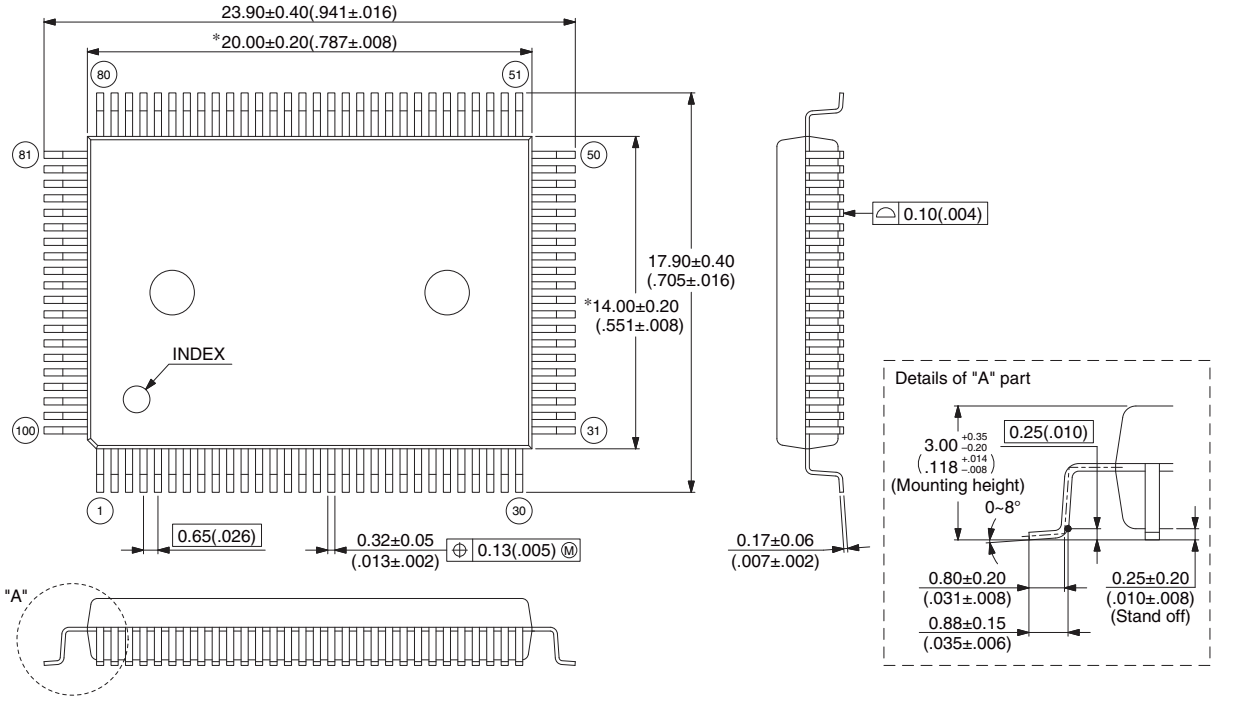
Mode	Selected Source Clock	Clock/Regulator Settings
Timer mode	PLL	CLKMC = 4 MHz, CLKPLL = 56 MHz (System clocks are stopped in this mode) Regulator in High Power Mode, Core Voltage = 1.9 V
	Main osc.	CLKMC = 4 MHz (System clocks are stopped in this mode) Regulator in High Power Mode, Core Voltage = 1.8 V
	RC clock fast	CLKRC = 2 MHz (System clocks are stopped in this mode) Regulator in High Power Mode, Core Voltage = 1.8 V
	RC clock slow	CLKRC = 100 kHz (System clocks are stopped in this mode) Regulator in High Power Mode, Core Voltage = 1.8 V
	Sub osc.	CLKSC = 100 kHz (System clocks are stopped in this mode) Regulator in Low Power Mode A, Core Voltage = 1.8 V
Stop mode	stopped	(All clocks are stopped in this mode) Regulator in Low Power Mode B, Core Voltage = 1.8 V

17. Package Dimension MB96(F)34x QFP 100P

100-pin plastic QFP		
	Lead pitch	0.65 mm
	Package width × package length	14.00 mm × 20.00 mm
	Lead shape	Gullwing
	Sealing method	Plastic mold
	Mounting height	3.35 mm MAX
	Code (Reference)	P-QFP100-14×20-0.65
(FPT-100P-M22)		

100-pin plastic QFP
(FPT-100P-M22)

Note 1) * : These dimensions do not include resin protrusion.
Note 2) Pins width and pins thickness include plating thickness.
Note 3) Pins width do not include tie bar cutting remainder.



Dimensions in mm (inches).
Note: The values in parentheses are reference values.